CREATIVE DETECTOR SOLUTIONS





THE GOLD STANDARD IN SILICON DRIFT DETECTORS



PHILOSOPHY AND VALUES

With our detectors the world is getting to the bottom of materials for engineers, scientists and other curious people. At KETEK in Munich, Germany, an experienced team of highly motivated engineers, physicists and technicians is developing and manufacturing a unique product portfolio around the Silicon Drift Detector, starting from the bare silicon wafer to the detector chip and further to the highly complex detector module.

MANAGEMENT

SILVIA WALLNER

Managing Director "Not everything important is measurable, and not everything measurable is important." Albert Einstein (1879 – 1955)



DR. REINHARD FOJT Managing Director

"The one thing that matters is the effort." Antoine de Saint-Exupéry (1900 – 1944)

DR. JÜRGEN KNOBLOCH Managing Director "What you want to ignite in others must first burn inside yourself."

Aurelius Augustinus (354 – 430)





We are offering our customers, located

everywhere in the world, tailored solutions

for their analytical devices and applications,

including our in-house-developed analog

and digital signal processing electronics. As a

100 % independent family enterprise, KETEK

has very close relationships with local uni-

versities to maintain its innovative strength.

With its high degree of production automation

we are a powerful and reliable OEM supplier

VITUS SDD MODULES

KETEK's VITUS Silicon Drift Detectors (SDD) are the state-of-the-art X-ray detectors for the energy range between 0.05 keV and 30 keV. They are used in applications such as EDS, XRF, μ XRF, and TXRF in bench top spectrometers, as well as in handheld systems. Due to their wide operating temperature range, their excellent energy resolution, and high reliability they are particularly suited for industrial applications.



UNPRECEDENTED LOW-ENERGY PERFORMANCE DOWN TO Li @ 53 eV

Energy resolution FWHM down to 126 eV for Mn K $_{\alpha}$ at 1 μs peaking time even for H150



Energy resolution FWHM down to 123 eV for Mn K_a at 3 μ s peaking time

-250000

-200000

150000

100000

50000

9 10

Excellent performance at low energies: FWHM of 42 eV for Carbon K_{α} line

Low-energy spectrum acquired with VITUS SDD showing the Lithium and Oxygen K_{α} lines





VITUS SDD INNOVATION

KETEK's R&D team constantly works on improving the VITUS SDD. The latest generation combines two recent developments: improved cooling performance and KETEK's patented graphene window. These modules have a significantly lower power consumption and an improved long-term stability, but also a better photon transmission compared to the previously used Beryllium window.

POWER

CONSUMPTION

2.5

- >20 K lower chip temperatures over the whole temperature range
- -60 °C at +65 °C heat sink temperature achievable
- Drastically increased efficiency of the thermoelectric cooling
- Improved heat management within module
- Ultra stable vacuum integrity for many years of operation





- CH window: 900 nm Carbon without support grid (replaces the 8μm Beryllium window)
- CL window: 150 nm Carbon with Si support grid (86% open area) for low-energy applications
- No fluorescence lines (pure Carbon window)
- Both window types compatible with vacuum encapsulation process
- Transmission better than conventional window types over the whole energy range



PORTFOLIO VITUS STANDARD

ASIC > 15000

PORTFOLIO LOW ENERGY

VALID FOR ALL SDDS

Amplification stage:					
Guaranteed P/B:					
Guaranteed P/T:					
Max. ICR @ 50 % DT:					
Absorption depth Si:					
On-chip collimator:					

COOLING PERFORMANCE [K]

(max. Δ T @ 20 °C heat sink)

LIMATED AREA

> 2000 1 Mcps 450 μm Multilayer

HOUSING

- 6

90

90



100

25 µm Be

≤ 136

90

65

СН

≤ 129

90

170

25 µm Be

≤ 136

90

KETEK'S UNIOUE

VERY LARGE

VITUS

ENSITI DOWN TO BORON K_{α} at 185 eV

		P	P	
	H7LE	H20LE	H30LE	H50LE
COLLIMATED AREA [mm ²]	7	20	28	47
ACTIVE AREA [mm ²]	13	30	41	65
WINDOW	CL	CL	CL	CL
GUARANTEED FWHM Mn K _{α} @ 5.9 keV [eV]	≤ 129	≤ 129	≤ 129	≤ 129
COOLING PERFORMANCE [K] (max. Δ T @ 20 °C heat sink)	90	90	90	90

H7 H20 H30 COLLIMATED AREA [mm²] 28 7 20 ACTIVE AREA [mm²] 13 30 41 WINDOW СН СН СН **GUARANTEED FWHM** ≤ 129 ≤ 129 ≤ 129 Mn K_α @ 5.9 keV [eV]

90

SDD PRODUCTION

VITUS SDD modules and the corresponding electronics are produced by KETEK in our modern production facilities in Munich, Germany. A reliable volume fabrication with a high degree of automation and maximum yield are essential to deliver quality products to our customers on-time. KETEK's value chain comprises all steps from the bare silicon wafer to the fully encapsulated detector module as well as complete signal processing electronics.











Fully automated module production



SDD TESTING

All KETEK products have to pass several quality gates during production to ensure a high vield and excellent quality. Most of the automated test equipment is designed by KETEK's test system development team.



Test of leak-tight encapsulation



Spectroscopic test of complete systems

OPTICAL INSPECTIONS & WAFER LEVEL MEASUREMENTS

The first quality gate – after semiconductor chip production includes optical inspections and electrical measurements. Therefore after dicing only good dies will be passed on to module production.

First quality gate on die level



TEST OF OPEN SDD MODULES

After assembly, still before encapsulation, 100 % of the modules are comprehensively tested and spectroscopically characterized for the first time. This is essential for a high yield, but also necessary because some of our modules are used windowless, e.g. in electron microscopes.

Spectroscopic test before encapsulation

VACUUM ENCAPSULATION

The next production step is the vacuum encapsulation of the modules, followed by two further quality gates: ensuring the hermetically sealing and the final spectroscopic test. The SDDs are now ready for shipment or they are passed on to our electronics production for further assembly.

SPECTROSCOPIC TESTING

The final test for our electronics systems, like the VIAMP or the AXAS, is another spectroscopic characterization including measurements with different parameter settings. For customized solutions we measure against agreed specifications and share the acquried data.



Spectroscopic characterization after encapsulation



Fully automated final testing



SDD ELECTRONICS

KETEK offers electronics engineered particularly for operating VITUS SDDs. The portfolio ranges from single components as the preamplifier to complete systems which further include all power supplies and the digital pulse processor. In combination with our tailored electronics solutions we ensure unprecedented performance with regards to FWHM and peak-to-background at ultra short peaking times down to $0.1 \,\mu s$ as well as input count rates up to 1 Mcps at 50% dead time.

() TAILORED DOWN TO 0.1 µs

STANDARD COMPONENTS FOR OUTSTANDING PERFORMANCE

120

0

1

2 3

Throughput with KETEK signal processing electronics at various peaking times and dead time < 50%



The energy resolution of a system with KETEK's DPP is independent from the input count rate, no matter which peaking time is chosen. This is essential for stable performance of a spectroscopic system.



Energy resolution at various chip temperatures acquired with VICO-DV 2.0 and VIAMP-KC H20





4

Peaking Time [µs]

5

6

7

KC VIAMP SDD ELECTRONICS



DV 2.0 **VICO**



The VIAMP-KC module is the combination of a low noise preamplifier and a VITUS SDD, matching all types from 7 mm² (H7) up to 50 mm² (H50) collimated area. The Al housing is functioning as an appropriate heat sink. Dual FFC cable connection for readout and parameter settings.

- Ultra-low-noise preamplifier
- Ramped reset type output signal
- Configurable via FFC interface
- SDD temperature readout
- Customized solutions available on request



- Extremely small dimensions 60×32×17 mm³
- Access to analog preamplifier signal and SDD temperature monitor
- Very low typical power consumption < 2 W</p>

mannin

- Wide unipolar voltage input range: +5V to +12V
- USB 2.0, SPI and RS232 interfaces
- SDD operating temperature setting, spectrum readout and power save mode accessible via software

The complement of the VIAMP module is the VICO-DV 2.0, comprising KETEK's proven digital pulse processor (DPP), a temperature controller and all voltage supplies for the SDD. Various parameters can be set and read out via software interface (DLL included). Its small dimensions allow an easy system integration. Also an analog version without DPP is available.

MATCHBOX SIZE SIGNAL PROCESSING ELECTRONICS

FOR SDDS

VIAMP-KC and VICO-DV 2.0 with FFC cable connection

2.0 AXAS SDD COMPLETE SYSTEM

OPERABLE AT AMBIENT TEMPERATURES UP TO + 50°C

Original size

The AXAS 2.0 is KETEK's new complete system for VITUS SDDs in a very compact housing. It includes all power supplies, the low-noise preamplifier, a high precision temperature controller and KETEK's fast DPP. Beside the digital signal also the analog preamp output is accessible. The AXAS 2.0 is available with all sizes of VITUS SDDs from H7 to H150 and different lengths of the vacuum tight finger.

NEW AXAS 2.0 XRF SYSTEM

■ Smallest complete XRF system on the market: 80×60×36 mm³

■ Low weight: < 300 g

■ Wide input voltage range: +5 V to +12 V / 1 A max.

Excellent cooling performance even at ambient temperatures up to 50 °C

Software interface for parameter setting, spectrum readout and power save mode



VA560 ARRAY MULTI-CHANNEL

SDD **ACCESSORIES**

SDD

Complete XRF multi-channel system including seven fast VITUS H80 SDDs, ultra-low-noise preamplifiers and seven high-performance digital pulse processors. Also part of the system is an external control unit with all power supplies and a cooling circuit. The whole architecture is very service friendly and allows an easy exchange of single channels.

CHANNEL READO



60 mm²

AREA

View on the SDD array head (cap removed)

- $7 \times 80 \text{ mm}^2 = 560 \text{ mm}^2$ collimated area
- FWHM < 139 eV @ 1 µs peaking time for Mn K_{α}-line (typ. < 132 eV)
- Operable at short peaking times down to 0.1 μs
- Up to 7 Mcps detection rate of the full system @ 50% dead time
- For X-ray energy range from 1.5 keV to 30 keV

EMLCOL EXTERNAL COLLIMATOR

The clip-on mount for external multilayer collimators is suitable for all VITUS SDDs up to the H50. Different collimator apertures are available. The EMLCOL prevents the X-ray fluorescence of the SDD's cap material.



No stray lines from SDD cap

- Improved P/B and P/T
- Additional protection for the VITUS entrance window



ECGRID CARBON **PROTECTION GRID**

The pure carbon grid can be mounted within an instrument in front of the SDD in order to protect its fragile window from mechanical impact.

- Open area 75%
- Thickness 0.5 mm
- Withstands a static stress up to 50 N
- No fluorescence lines from grid material
- Customized shapes available on request

KETEK KETEK LANDS ON MARS

In Februar 2021, on board of Mars rover Perseverance, KETEK's Silicon Drift Detectors have arrived on the Red Planet once again. This is already the fourth space mission a VITUS SDD has been chosen by the NASA as XRF detector:

- Spirit 2004 2011
- Opportunity 2004 2018
- Curiosity landed 2012
- Perseverance landed 2021

MARS 2020 PERSEVERANCE

 Two KETEK H50-CUBE SDD modules are installed in the NASA PIXL experiment on board of the Mars Rover
VITUS SDDs have been fully qualified for space mission by NASA / JPL

QUALITY IN FOCUS KETEK

FULL COMMITMENT TO QUALITY OF ALL EMPLOYEES

Quality is the basis of all activities at KETEK and every employee contributes significantly to quality.

CLOSE COOPERATION WITH KEY CUSTOMERS

KETEK HEADQUARTERS

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